



The R&D for ATLAS pixels for sLHC

Marco Bomben

LPNHE



Outline



- Introduction
- LHC & ATLAS
- The LHC upgrade
- The Pixel upgrade
- The IBL project
- The R&D for a new Inner Detector: the Planar Pixel Sensor Upgrade (PPSU) project
- Conclusions



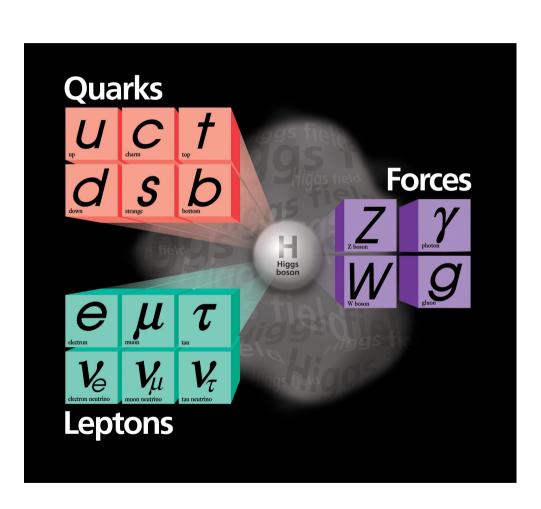


INTRODUCTION



The Standard Model (SM)





Matter is made out of fermions:

3 generations of quarks and leptons

Forces are carried by Bosons:

- Electroweak: γ,W,Z
- Strong: gluons

Higgs boson:

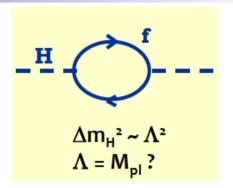
- Gives mass to gauge bosons via EW symmetry breaking
 - Not found yet



The SM limits



- Mass hierarchy problem
 - why the Higgs boson is so much lighter than the Planck mass?



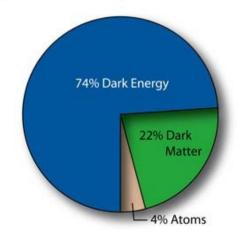
Now:

No antimatter now!

Matter / antimatter asymmetry

$$\eta_B \equiv \frac{n_B - n_{\overline{B}}}{n_{\gamma}} = \frac{n_B}{n_{\gamma}} =$$
Baryons
photons
$$= (6.1 \pm 0.3) \times 10^{-10}$$

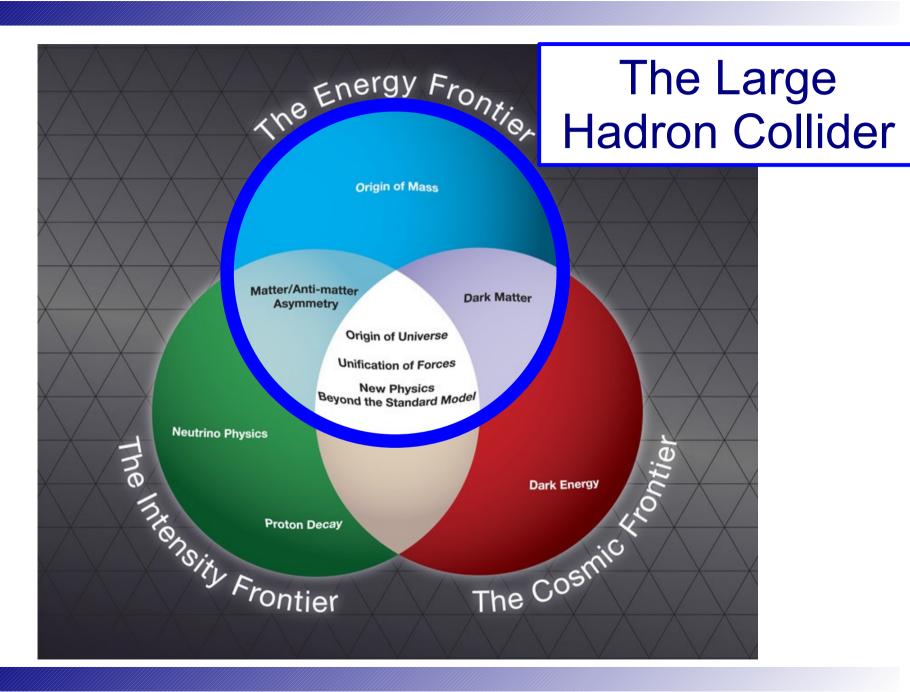
Dark matter & dark energy





How to address these problems?









LHC & ATLAS

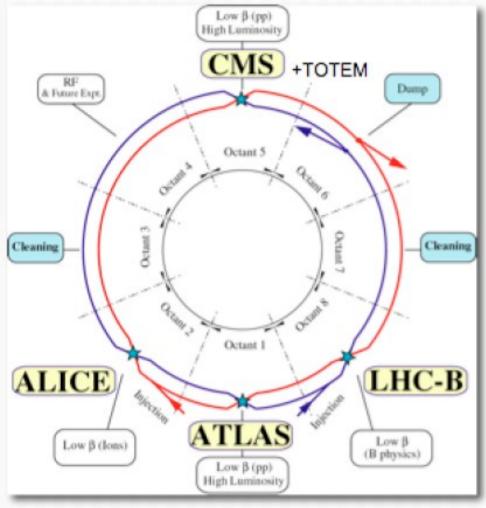


LHC in a nutshell





- 1232 superconducting dipoles
 - 15m long at 1.9 K, B=8.33 T
 - Inner coil diameter = 56 mm design
- beam-energy 7 TeV (7x TEVATRON)
- Luminosity 10³⁴ cm⁻²s⁻¹ (>100x TEVATRON)
- Bunch spacing 24.95 ns
- Particles/bunch 1.1 10¹¹
- Stored E/beam 350 MJ ~ 80kg of TNT
- Also: Lead lons operation
 - Energy/nucleon 2.76 TeV / u
 - Total initial lumi 10²⁷ cm⁻² s⁻¹

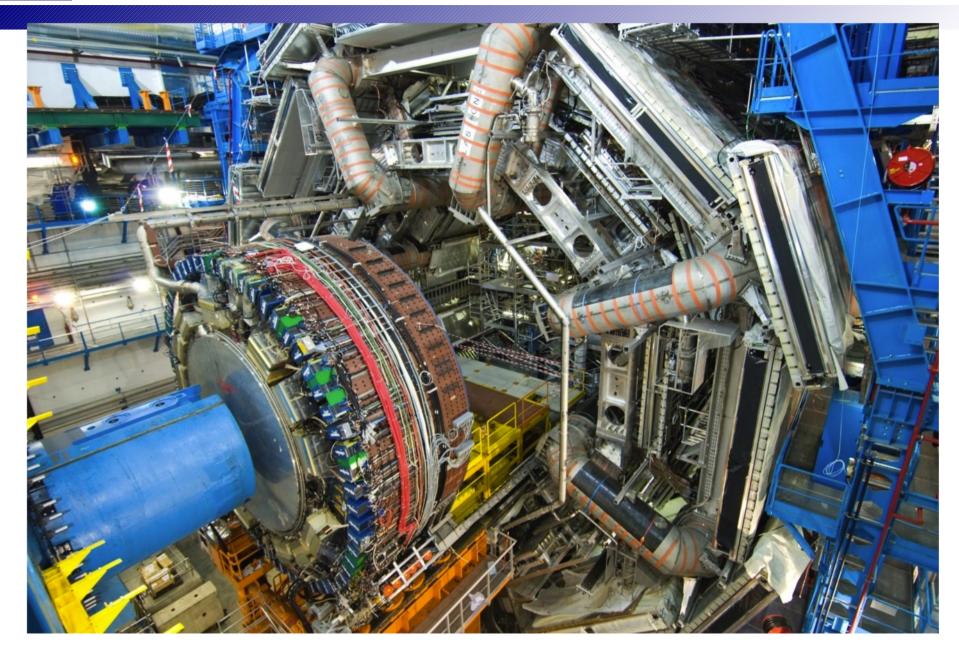


- 8 independent sectors
 - Challenge for control, powering
- 10 GJ stored in magnets
- Warm insertion regions for beam dump, cleaning, acceleration



ATLAS

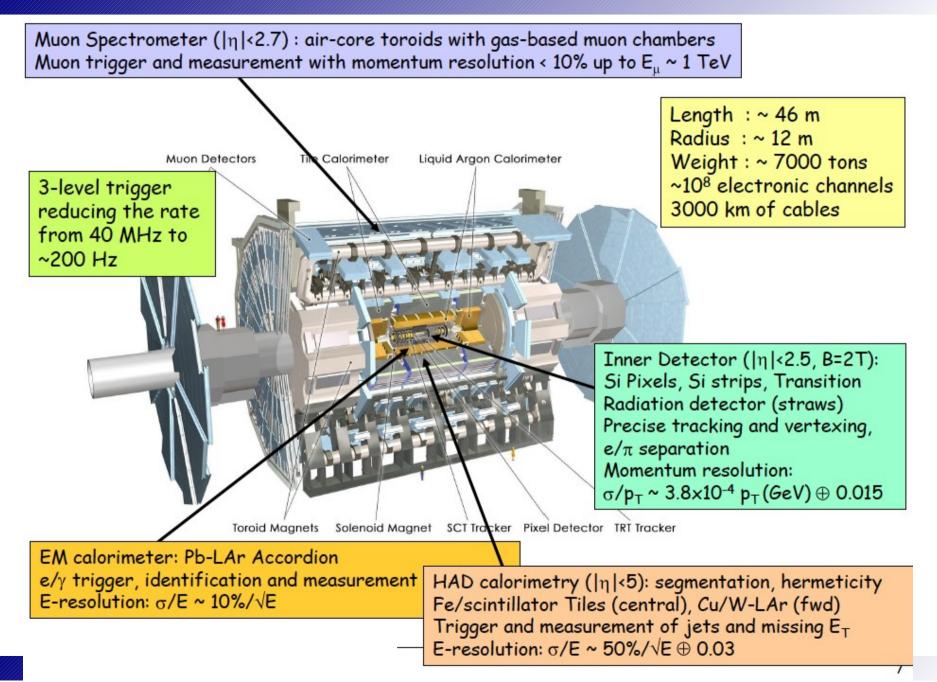






ATLAS facts

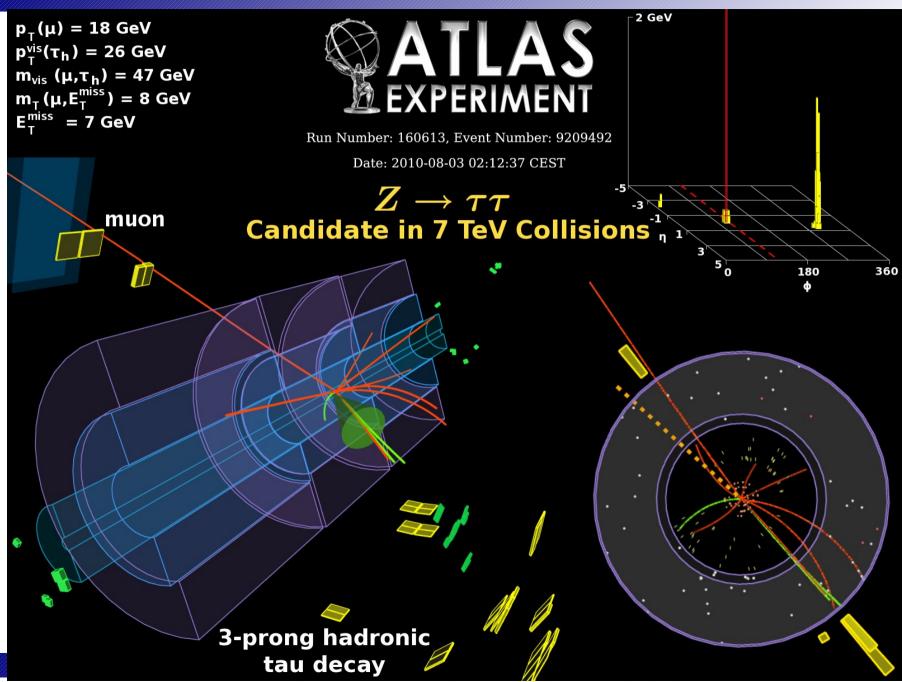






$Z \rightarrow TT$

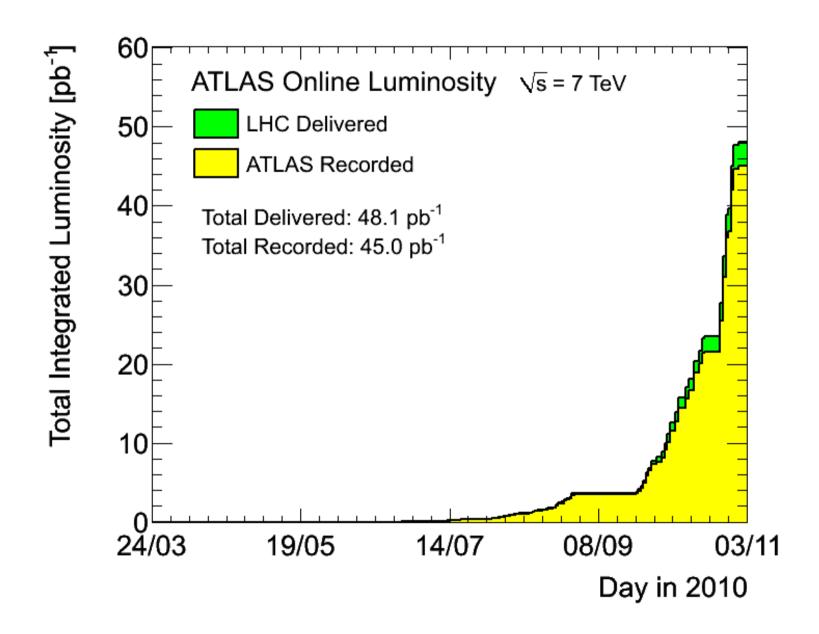






Integrated luminosity

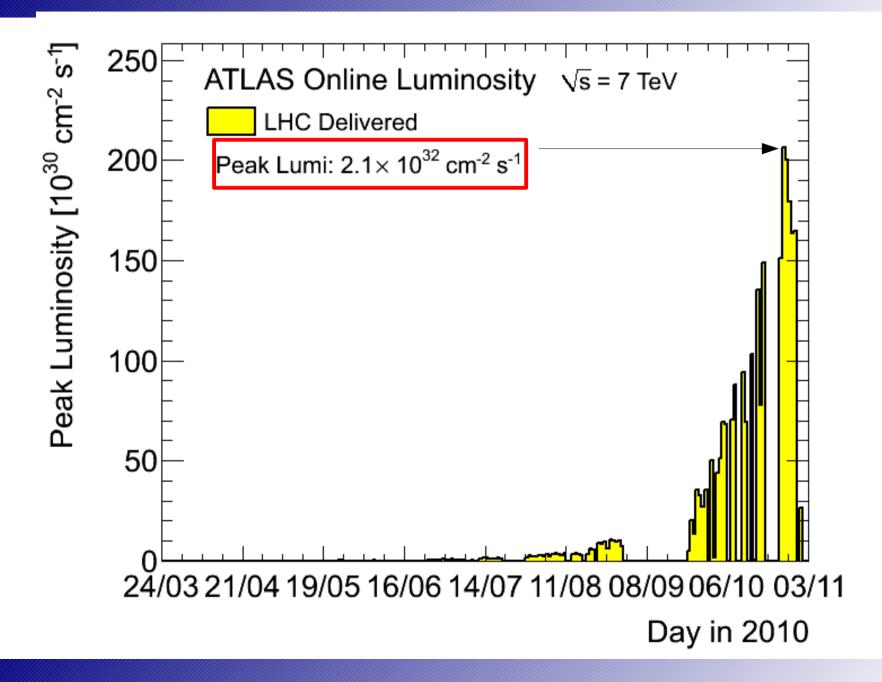






Peak luminosity







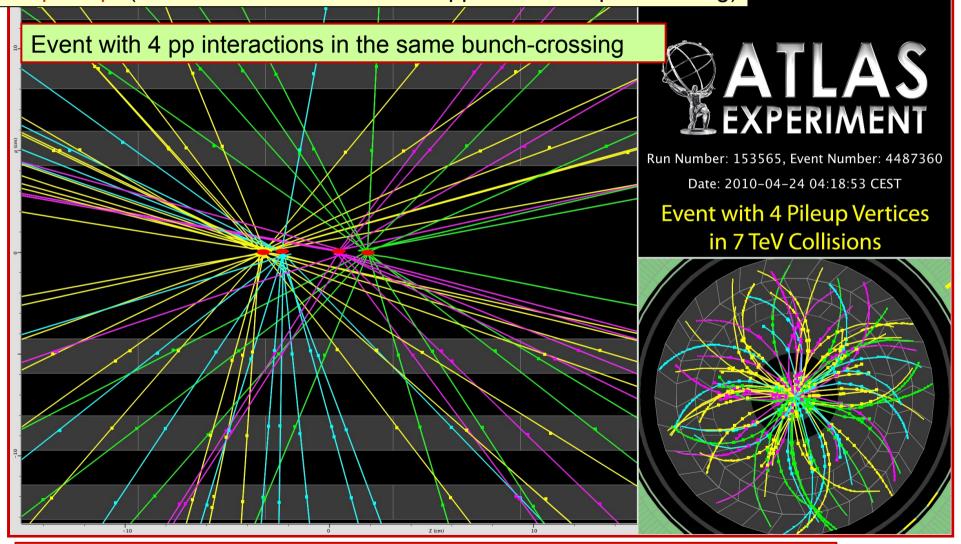
21/03/2011

Pile up



Max peak luminosity: L~1.6 x 10³⁰ cm⁻²s⁻¹

- → average number of pp interactions per bunch-crossing: up to 1.3
- → "pile-up" (~40% of the events have > 1 pp interaction per crossing)



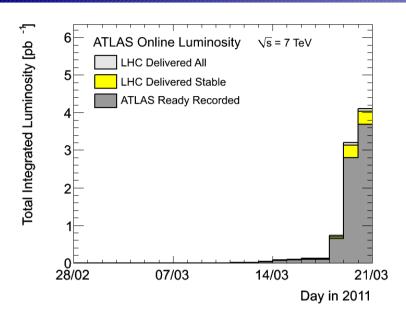
~ 10-45 tracks with p_T >150 MeV per vertex

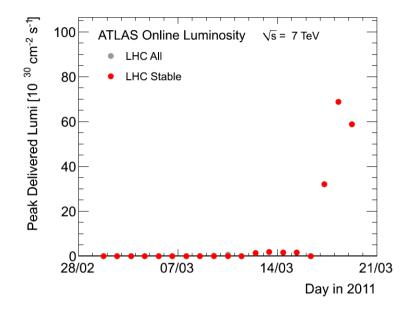
Vertex z-positions: -3.2, -2.3, 0.5, 1.9 cm (vertex resolution better than ~200 μm)

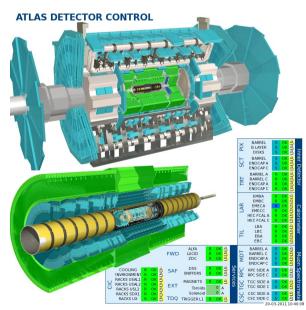


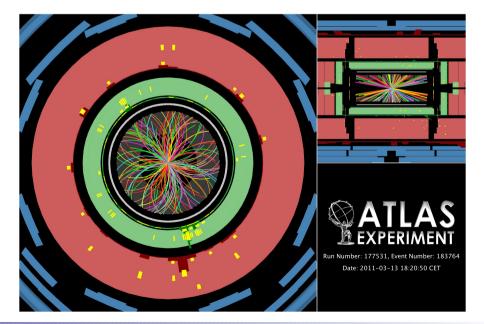
First 2011 collisions















LHC upgrade



The LHC in the high lumi area

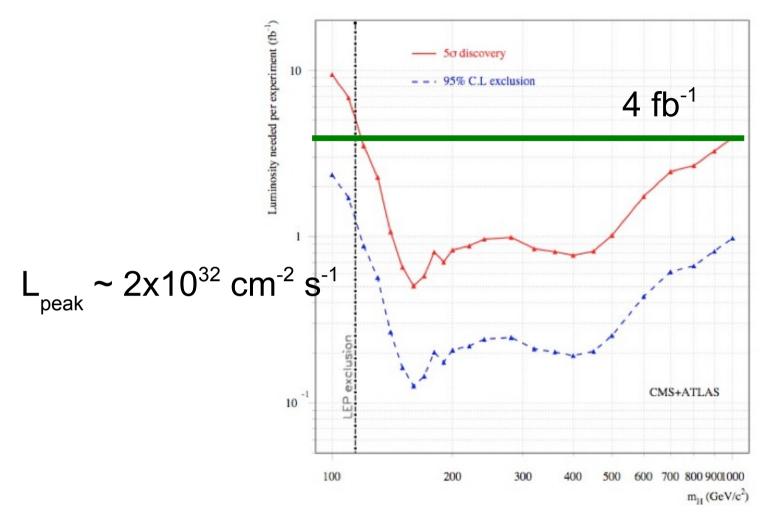


- We have seen that the LHC is a discovery machine built to study
- → The ElectroWeak Symmetry Breaking mechanism
- The shortcomings of the Standard Model
- The discovery potential of the LHC can be enhanced by increasing its luminosity
- Infact, whatever is discovered, we'll want, at least, to
- Improve the measurement of its properties (masses, couplings, etc)
- → Test further predictions of the theories put forward to explain it



Physics case for a sLHC





By 2011-12 we may have a good picture of the TeV-scale physics

"Within 2/3 years of data taking, the SM Higgs boson will be discovered, or entirely excluded, over the full mass range" The super-LHC review – M. Mangano

What can the LHC achieve with extended, higher luminosity operations (SLHC)?

- Improve measurements of new phenomena seen at the LHC. E.g.
 - Higgs couplings and self-couplings
 - Properties of SUSY particles (mass, decay BR's, etc)
 - Couplings of new Z' or W' gauge bosons (e.g. L-R symmetry restoration?)
- 2. Detect/search low-rate phenomena inaccessible at the LHC. E.g.:
 - $H \rightarrow \mu^{+}\mu^{-}, H \rightarrow Z\gamma$
 - top quark FCNCs
- 3. Push sensitivity to new high-mass scales. E.g.
 - New forces (Z', W_R)
 - Quark substructure

Energies/masses in the few-100 GeV range. Detector performance at SLHC should equal (or improve) in absolute terms the one at LHC

Very high masses, energies, rather insensititive to high-lum environment. Not very demanding on detector

performance Slightly degraded detector performance tolerable



The LHC in the future



Chamonix 2011 decisions:

- LHC running in 2012 to benefit from potential for reaching more than 5 fb⁻¹ before first long shut down.
- Remain at 3.5 TeV beam energy due to unacceptably high risks for machine operation at beam energies above 3.5 TeV

Peak lumi goal: $L = 1 \ 10^{34} \ cm^{-2} \ sec^{-1}$

- Prepare for 18 month long shutdown in 2013 2014
- Commissioning and operation at 7 TeV in 2015 and 2016
- **sLHC** Upgrade LHC in 2017 to be compatible with operation with above nominal beam intensities (LINAC4 & Collimation upgrade)

Peak lumi goal: $L \ge 5 \ 10^{34} \ cm^{-2} \ sec^{-1}$

ACES 2011 Workshop, CERN, March 2011

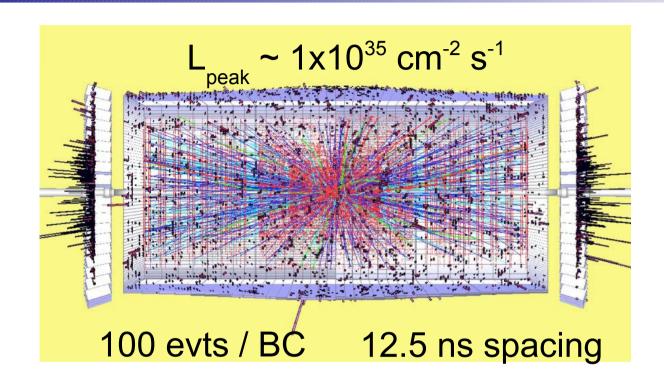
Oliver Brüning BE-ABP

8



High luminosity implications



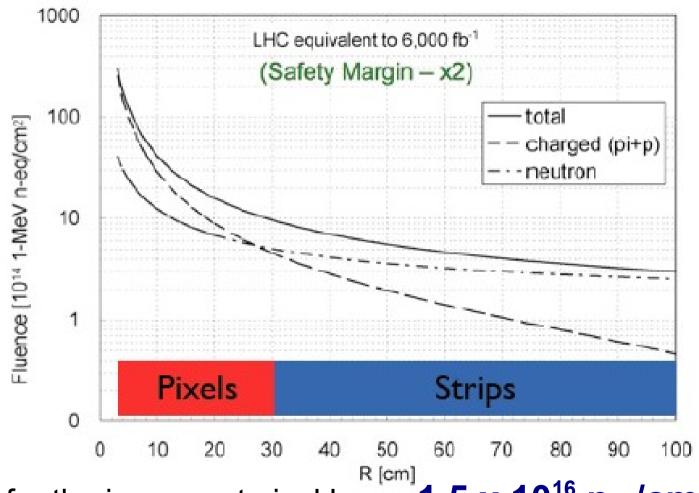


- More pile-up & higher rate events
- → Faster electronics
- → Higher granularity subdetectors



High luminosity implications





- fluences for the innermost pixel layer: 1.5 x 10¹⁶ n_{eq}/cm² (3 ab⁻¹)
- Radiation hard components



Macroscopic effects



Increase of leakage current

- can be helped with cooling

Change of the full depletion voltage V_{dep} (effective doping concentration N_{eff}).

every p-n-junction has a finite breakdown voltage

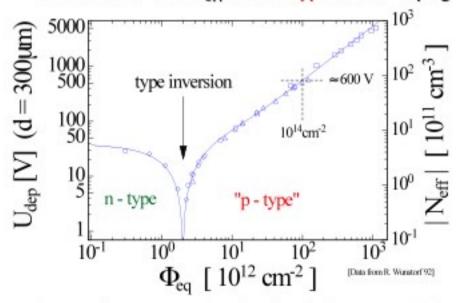
Decrease of the charge collection efficiency

- limited by partial depletion, trapping, type inversion

Change of the leakage current:

10⁻¹ n-type FZ - 7 to 25 KWm n-type FZ - 7 KWm [A/cm³] n-type FZ - 4 KWm □ n-type FZ - 3 KWm p-type EPI - 2 and 4 KWm n-type FZ - 780 Wm 10^{-4} n-type FZ - 410 Wm n-type FZ - 130 Wm 10-5 n-type FZ - 110 Wm n-type CZ - 140 Wm p-type EPI - 380 Wm 10^{13} 10^{11} 10^{12} Φ eq [cm⁻²] [MMoll PhD Thosis]

Evolution of the N_{eff} for n-type initial doping:

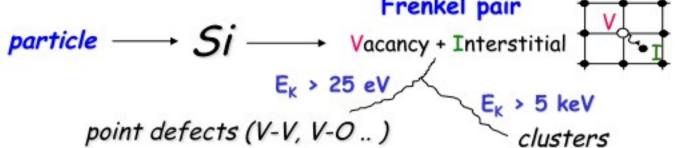


Panja Luukka, The Fifth International Forum on Advanced Material Science and Technology (IFAMST5 2006)

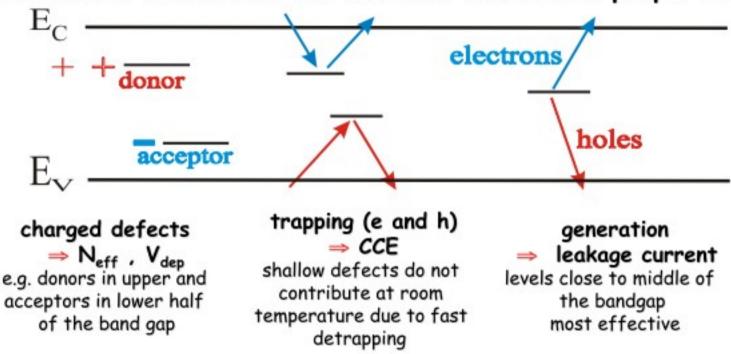


Radiation damage in silicon detectors





Influence of defects on the material and device properties



Panja Luukka, The Fifth International Forum on Advanced Material Science and Technology (IFAMST5 2006)



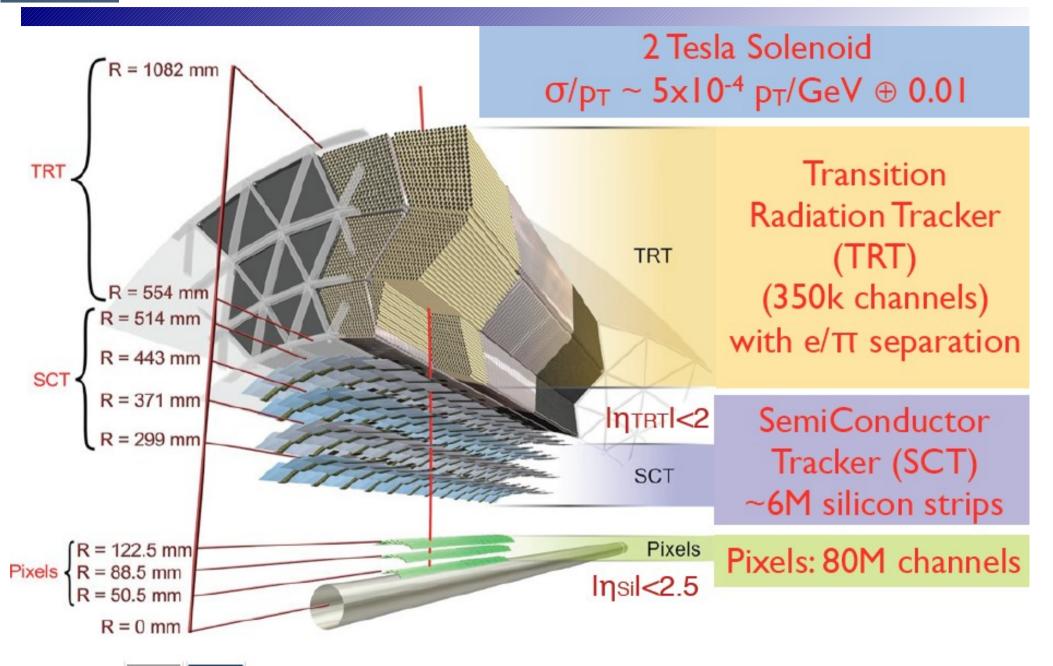


THE PIXEL UPGRADE



The current Inner Detector

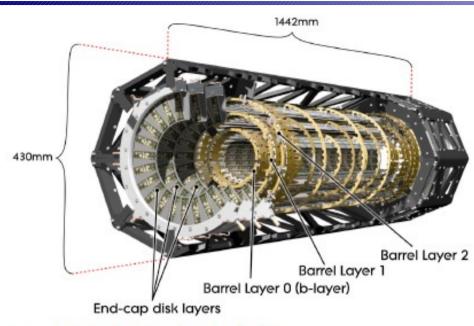






The current ATLAS Pixel detector



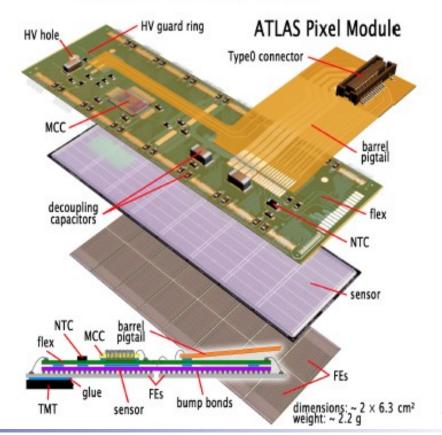


ATLAS Pixel Module

- 16 front-end chips (FE-I3) module with a Module Controller Chip (MCC)
- 46080 R/O channels 50 μm x 400 μm (50 μm x 600 μm for edge pixel columns between neighbour FE-I3 chips)
- Planar n-in-n DOFZ silicon sensors,
 250um tick
- Designed for 1 x 10¹⁵ 1MeV fluence and 50 Mrad
- Optolink R/O: 40÷80 Mb/link

ATLAS Pixel Detector

- 3 barrels + 3 forward/backwarc disks
- 112 stave and 4 sectors
- 1744 modules
- 80 million channels

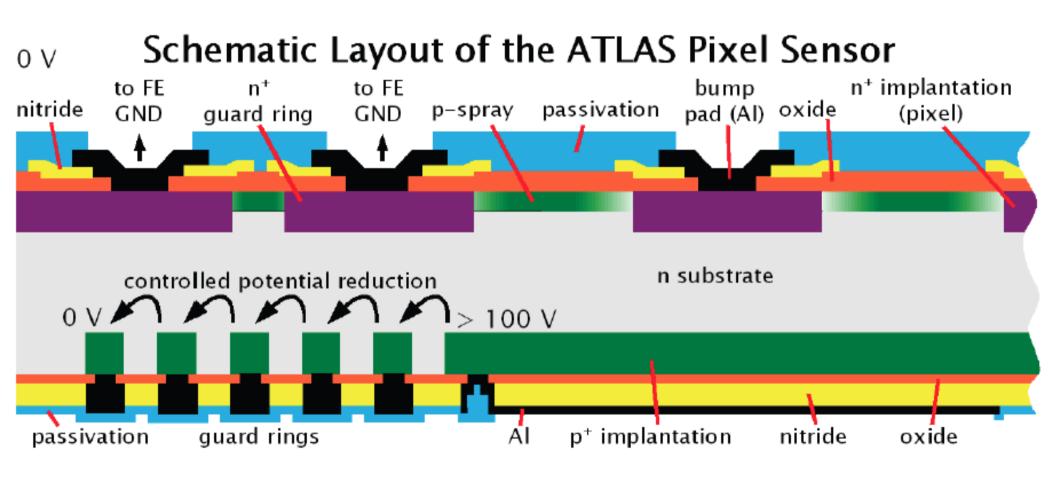


IPRD10, Siena 9.6.2010 - Alessandro La Rosa (CERN)



The ATLAS Pixel Sensor

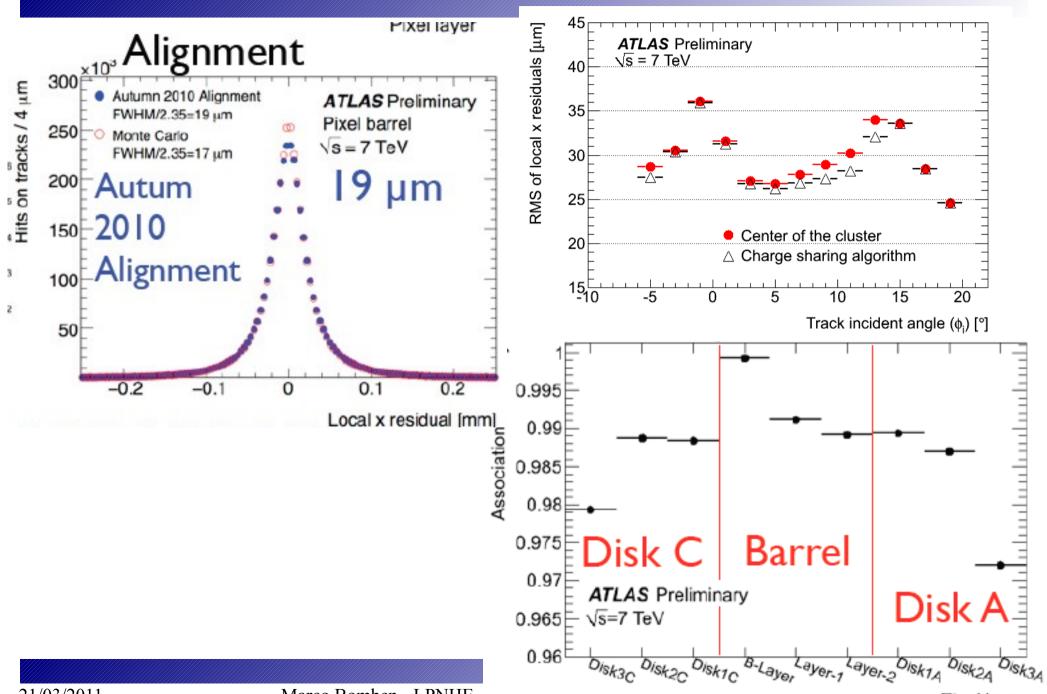






Pixel performances









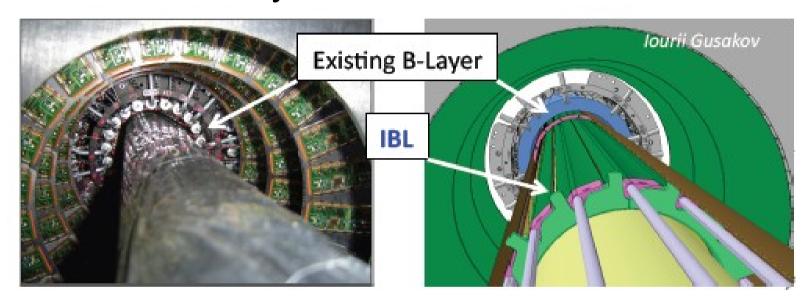
THE INSERTABLE B-LAYER



A 4th pixel layer: Insertable B Layer



 Add a 4th low-mass Pixel layer inside the present B-layer: the Insertable B-Layer



3.2 cm from IP

- To improve performance of existing system
- To maintain performance of existing system when present B-layer starts degrading

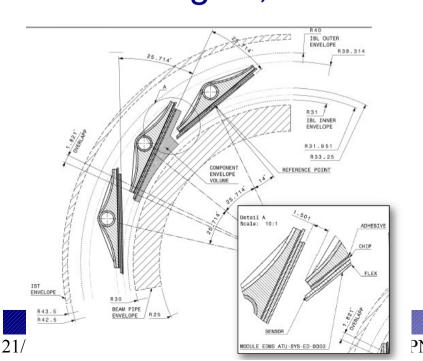
Scheduled for 2013

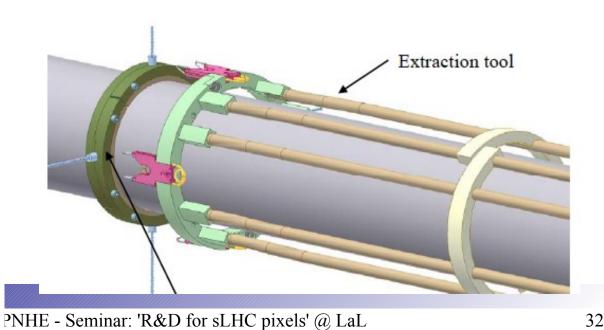


Why is IBL important



- This will be the first real upgrade project in the community
- Most of the problems and technologies necessary later for sLHC will be tested and solved already. Excellent test bench for later.
- → The IBL is the "technology" bridge to sLHC. Its specification required us to develop and use new technologies, which are directly relevant for sLHC

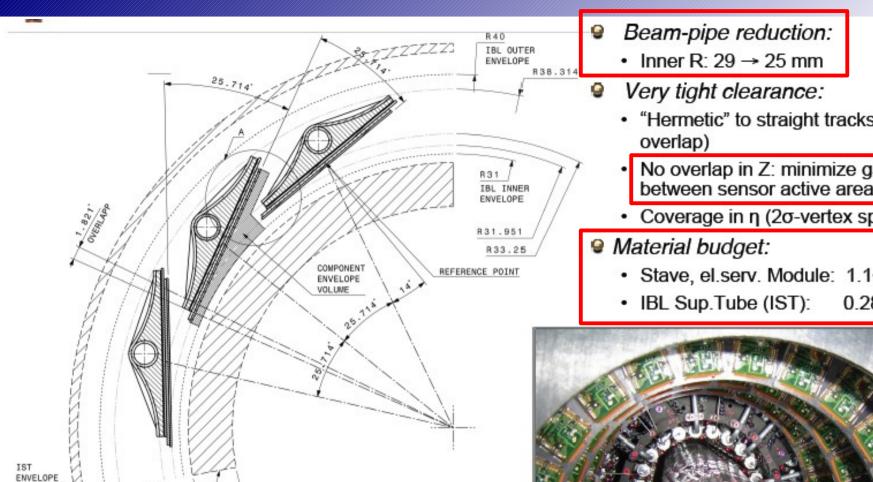






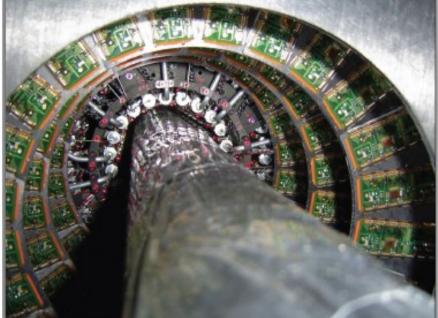
IBL - layout





- Beam-pipe (BP) extracted by cutting the flange on one side and sliding (guiding tube inside).
- IBL Support Tube (IST) inserted.
- IBL with smaller BP inserted in the IST

- "Hermetic" to straight tracks in Φ (1.8°
- No overlap in Z: minimize gap between sensor active area.
- Coverage in η (2σ-vertex spread): 2.6
- Stave, el.serv. Module: 1.16 % X₀
- $0.28 \% X_0$



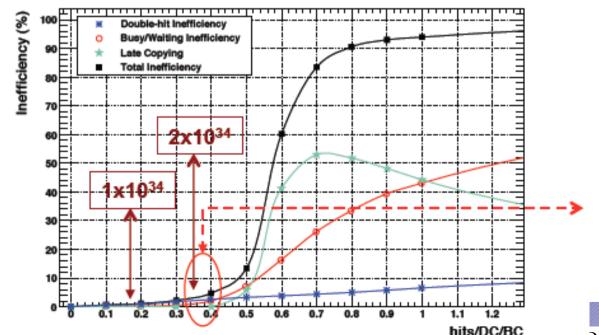


IBL - Luminosity effects



- The current Pixel R.O. designed for a peak luminosity of 1 x 10³⁴ cm⁻²s⁻¹.
- · A luminosity at least twice that high is expected before the sLHC end
- Event pileup: redundancy in track measurement to control the fake rate
- High occupancy: induce readout inefficiencies
- Affects the B-layer more than other layers
- Would thereby limit the b tagging efficiency.
- IBL: low occupancy (with respect to SCT/TRT) reduces track fakes
- FE-I4 has higher bandwidth than existing readout.





FE-I3 has 5% inefficiencies at the Blayer occupancy for 2.2x10³⁴. Steep rising function of occupancy: no safety margin.

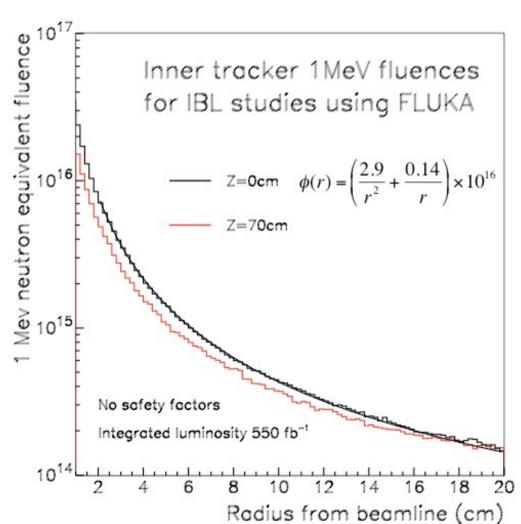


IBL – Radiation effects



IBL designed for 550 fb⁻¹ (provides margin should luminosity evolve more rapidly than expected or should 2020 HL-LHC shutdown be delayed)

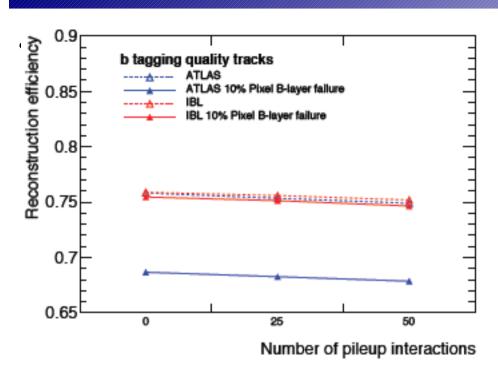
- NIEL dose @ 3.2 cm:
 3.3 x 10¹⁵ n_{eq}/cm²
- Safety factor: 5 x 10¹⁵ n_{eq}/cm²
 - TID: 250 Mrad



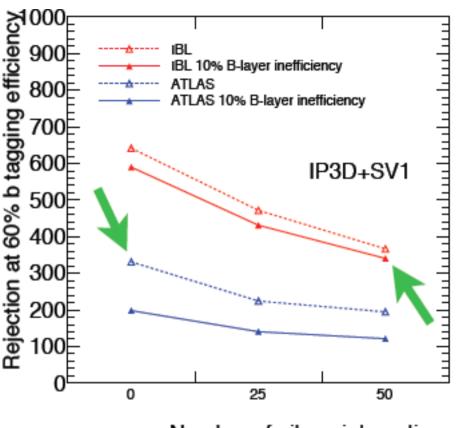


IBL performances





In a scenario with a 10% cluster inefficiency in the actual B-layer, the IBL recovers tracking efficiency and impact resolution



Number of pileup interactions

- Only minor effect on b-tagging performances
- Performing better than ATLAS w/o defects and pileup!

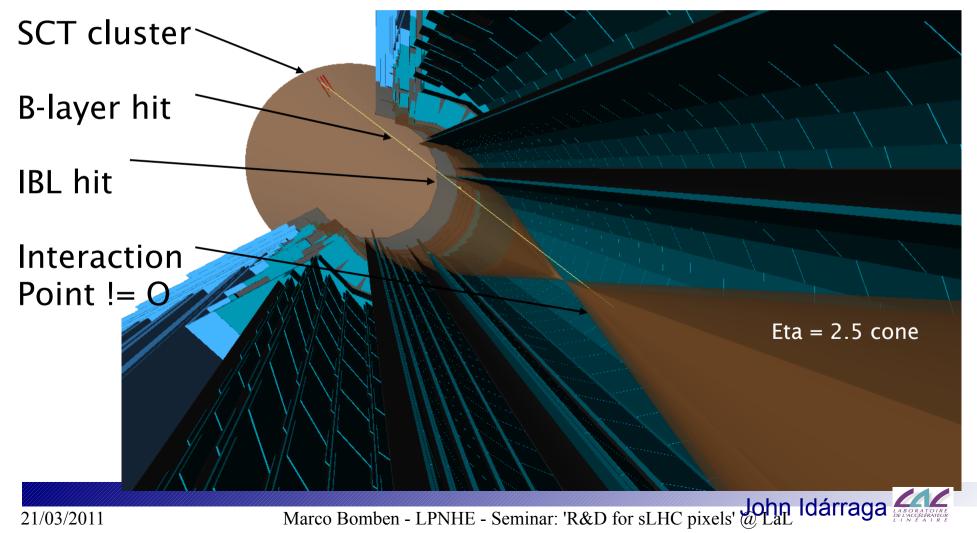


Montecarlo studies on IBL





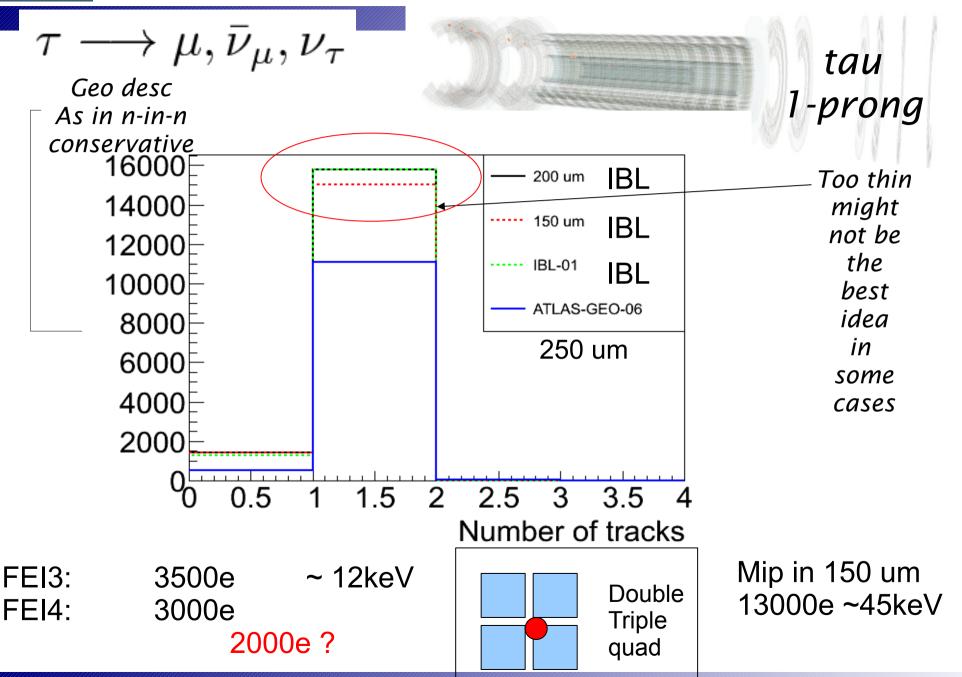
Montecarlo studies performed by the PPS group @ LAL





$T \rightarrow 1$ prong

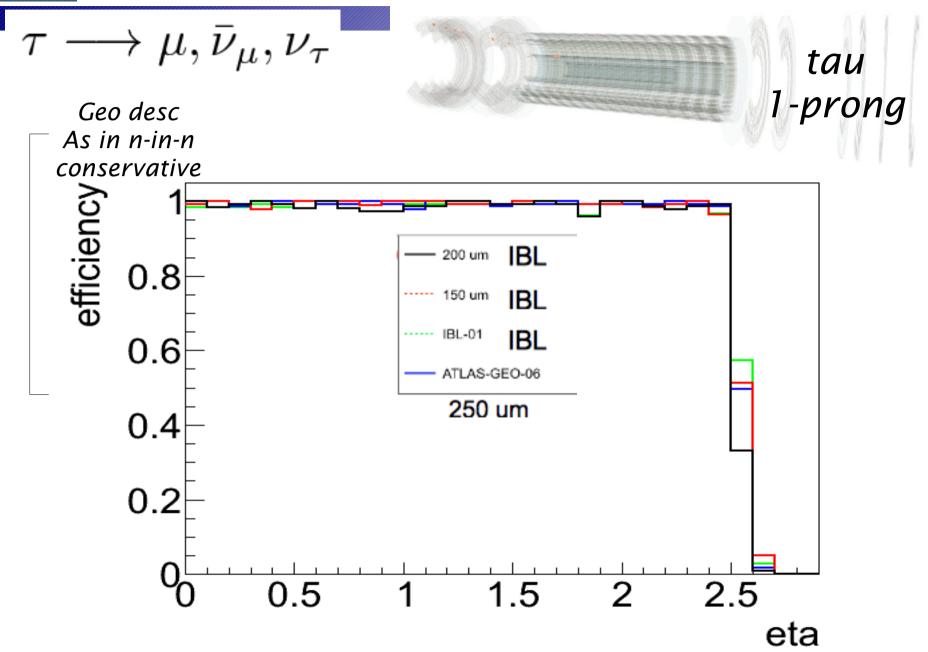






$\tau \rightarrow 1$ prong

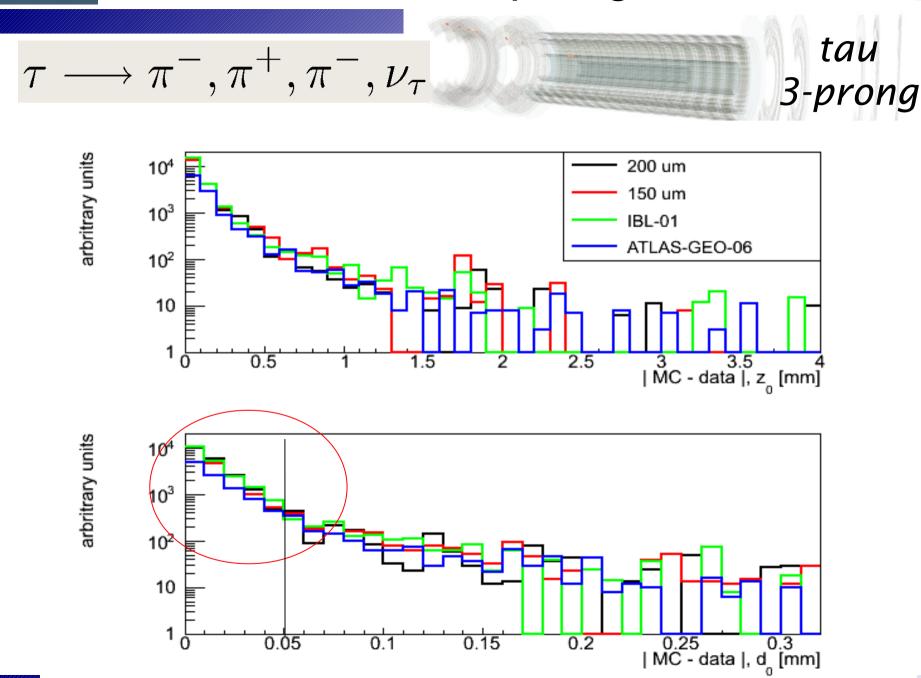






$\tau \rightarrow 3$ prong

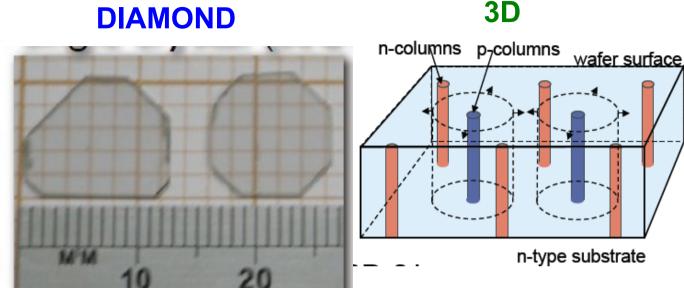






Sensor options for the IBL ...and sLH

 More details in the next slides



- Very low noise
- No cooling
- No doping needed
- Low capacitance
- Very high BD field
- Expensive
- Difficult to realize large sample of single crystal sensors

- Implants through the detector
- Highly segmented sensor
- Low depletion voltage
- Fast signal
- High rate capable
- Inefficiency regions corresping to column
- Low cost large production to be proven





THE PLANAR PIXEL UPGRADE



The ATLAS Planar Pixel Sensor R&D

- Aim: Explore the suitability of planar pixel sensors for highest fluences
- Approved ATLAS R&D project since 2009: 17 institutes, > 80 scientists

ATLAS	R&D on Planar Pixel Sensor Technology for the ATLAS Inner Detector Upgrade		
ATLAS Upgrade Document No:	Institute Document No.	Crested: 10/01/2008	Page 1 of 19
		Modified: 07/05/2009	Rev. No.: 1.1

IBL + Long Term (2017 or 2020)

D. Dobos, B. Di Girolamo, H.Pernegger, S. Roe, A. La Rosa¹, V. Vrba, P. Sicho, J. Popule, M.Tomasek, L. Tomasek, J. Stastny, M. Marcisovsky, M. Havranek, J. Bohm², A. Lounis, N. Dinu, M. Benoît, R. Tanaka³, G. Calderini, D. Lacour, H. Lebbolo, G. Marchiori, J. Ocariz, P. Schwemling⁴, M. Barbero, F. Hügging, H. Krüger, N. Wermes⁵, H. Lacker⁶, I. M. Gregor, U. Husemann, P. Kostka⁷, C. Gößling, R. Klingenberg, D. Münstermann, A. Rummler, G. Troska, T. Wittig, R. Wunstorf⁸, J. Grosse-Knetter, M. George, A. Quadt, J. Weingarten⁹, L. Andricek, M. Beimforde, A. Macchiolo, H.-G. Moser, R. Nisius, R. Richter, P. Weigell¹⁰, D. Cauz, M. Cobal, C. del Papa, D. Esseni, M. P. Giordani, P. Palestri, G. Pauletta, L. Selmi¹¹, Y. Unno, S. Terada, Y. Ikegami¹², M. Cavalli, I. Korolkov, M. Lozano, C. Padilla, G. Pellegrini, M. Ullan¹³, T. Affolder, P. Allport, G. Casse, T. Greenshaw, I. Tsurin¹⁴, M. Battaglia, T. Kim, S. Zalusky¹⁵, I. Gorelov, M. Hoeferkamp, S. Seidel, K. Toms¹⁶, V. Fadeyev, A. Grillo, J. Nielsen, H. Sadrozinski, B. Schumm, A. Seiden¹⁷

17 institutions:

¹CERN, ²AS CR, Prague, ³LAL Orsay/ University Paris-sud XI, ⁴LPNHE / University Paris VI, ⁵University of Bonn, ⁶HU Berlin, ⁷DESY, ⁸TU Dortmund, ⁹University of Goettingen, ¹⁰MPP and HLL Munich, ¹¹Università degli Studi di Udine – INFN, ¹²KEK, ¹³IFAE-CNM (Barcelona), ¹⁴University of Liverpool, ¹⁵UC Berkeley/LBNL, ¹⁶UNM, Albuquerque, ¹⁷UCSC, Santa Cruz

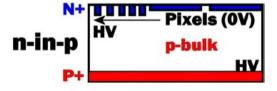


Why planar sensors?



- Planar pixel is a proven technology
 - the current n-in-n pixel detector.
 - Modules shown to work after 10¹⁵ neq/cm2

- n-in-n
 OV
 n-bulk
 HV
- If strips not adequate any more, pps would be the natural option
- Potential for a low-cost large-area production with n-in-p
 - Only one side is patterned
- Research directions
 - Radiation damage studies
 - Active area optimization and geometry redesign
 - Advanced simulation studies
 - High rate capable electronics
 - Low cost module production





TCAD simulation



- Technology Computer Aided Design offers the possibility to simulate the behavior of a sensor under several conditions
 - Reverse bias
 - Illuminated by light
 - At high/low temperature
 - As been exposed to high fluences
- And monitor the interesting quantities
 - IV / CV curves
 - GR potentials
 - CCE
 - Electric field

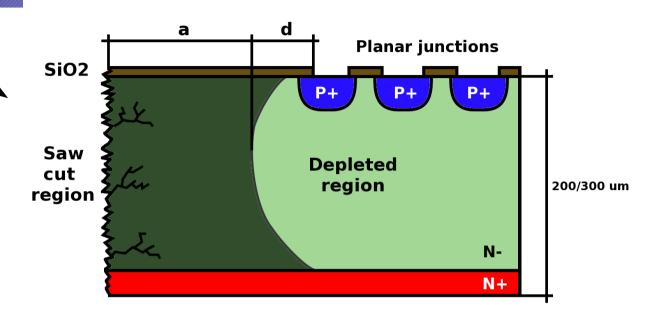
Simulation saves you money but needs very precise inputs to produce reliable information



Geometry - Dead edge



Dead edge is an inactive area whose porpouse is to protect the cut area (full of generation centers) from high electric field



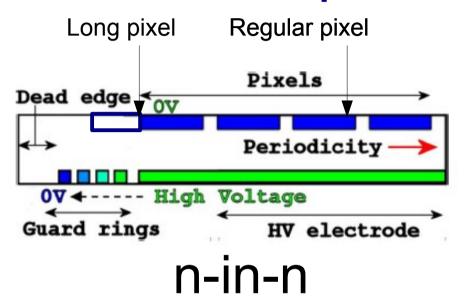
• "It is not possible to obtain the full geometrical coverage in z as the Pixel detector does, where modules are tilted in z and are partially overlapped, because there is not enough space. However the gap between modules is minimized using a sensor design with active or slim edges." IBL TDR

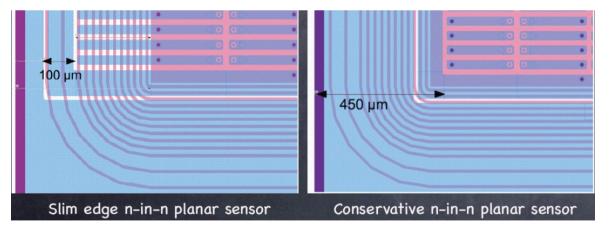


Geometry optimizations

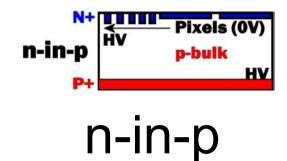


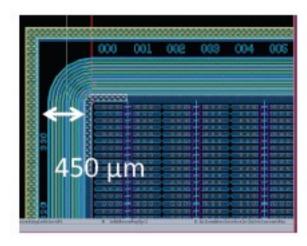
Attempt to recover active area





Longer pixel "under the guard-ring"





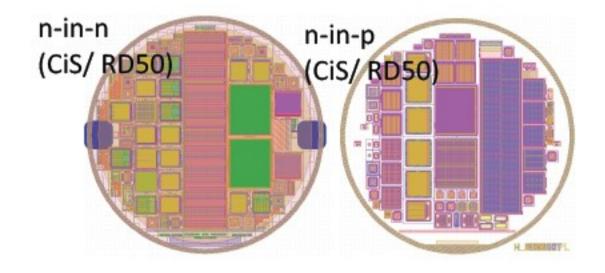
Reducing GRs structure width



First PPS sensor submission



 Based on an intense design and simulation work, a first submission of planar sensors was made

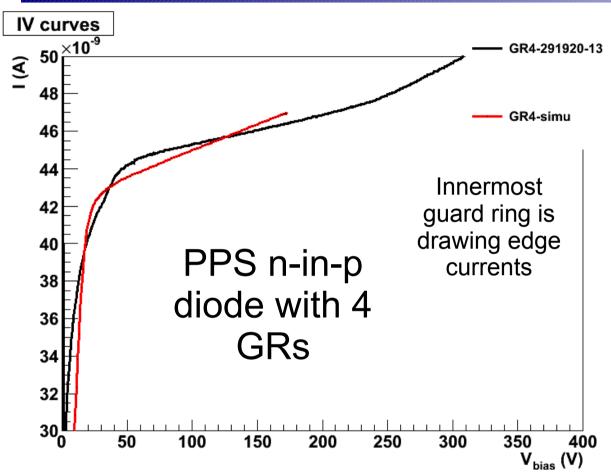


- Current ATLAS R.O.C. ("FE-I3") compatible sensors
- New ATLAS R.O.C. ("FE-I4") compatible sensors
- Diodes, test structures



Test on prototypes





Tuning for bulk concentration and generation lifetime for simulation



Measures were taken in our clean room

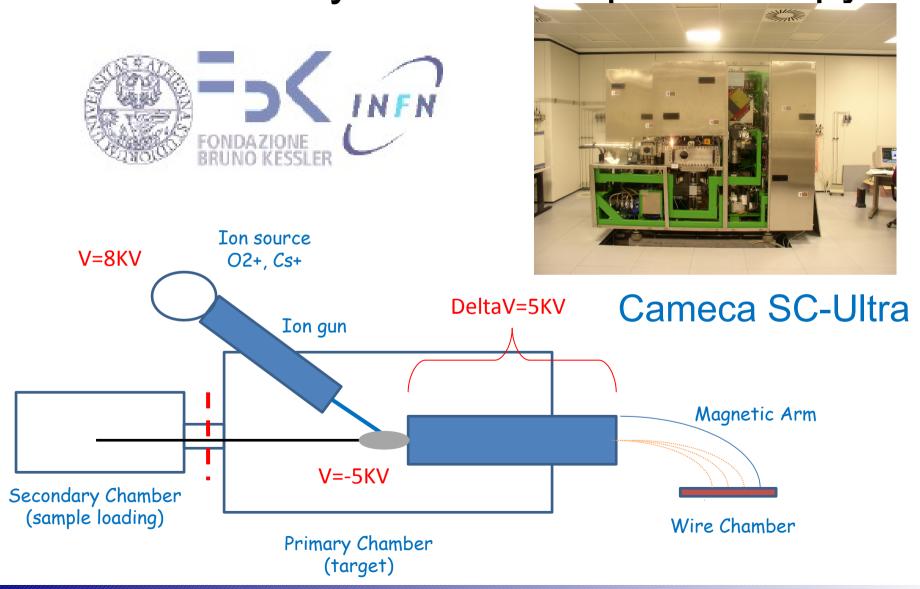




SIMS measurements



SIMS: Secondary Ion Mass Spectroscopy

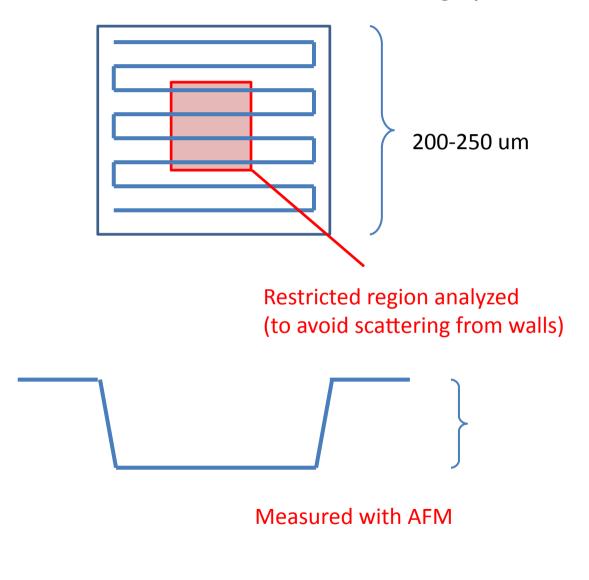


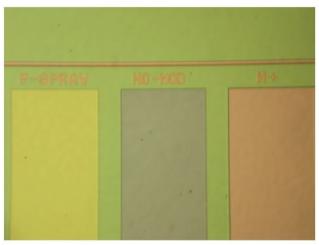


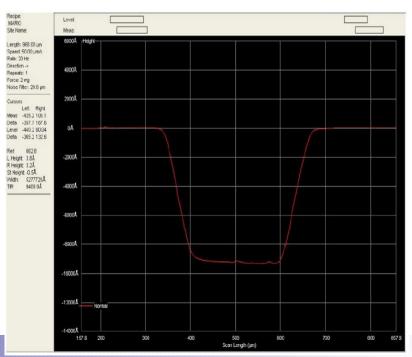
SIMS principle



An ion beam is scanning (and escavating the sample)



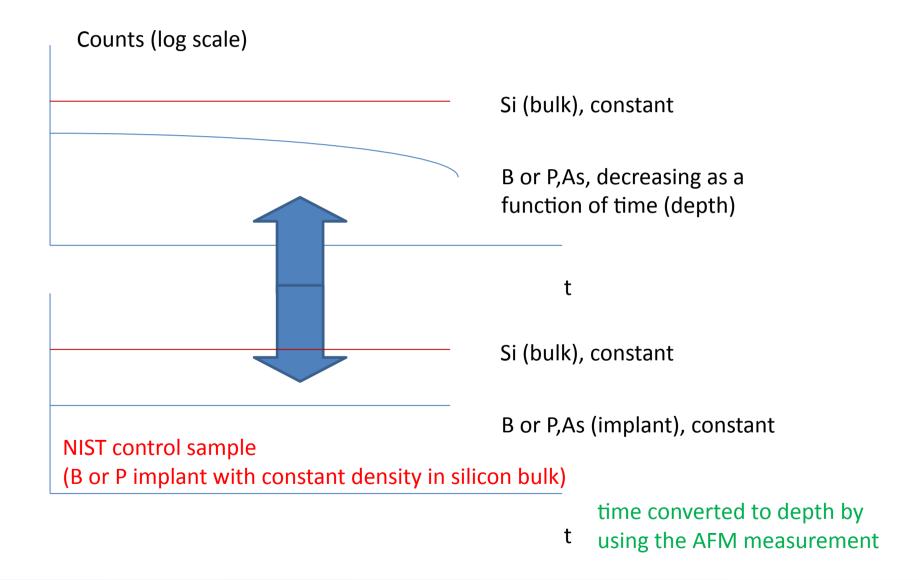






Doping profile measurement

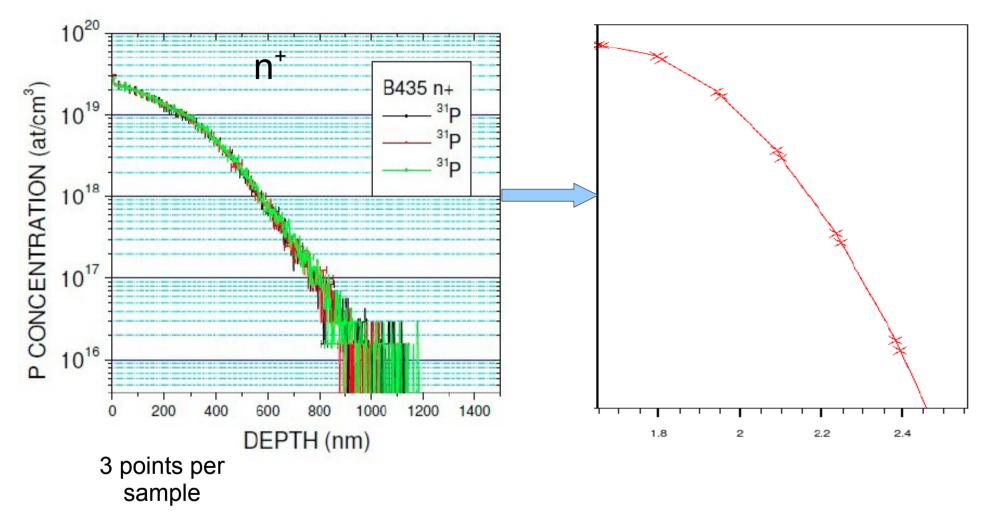






Example: pixel implant





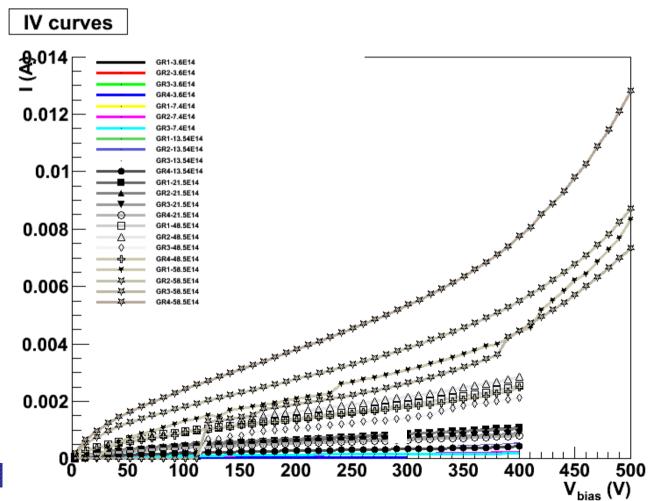
- Concentration profiles are used inputs for the simulation
 - Same for p+, moderate and non-moderate p-spray



Irradiation campaings



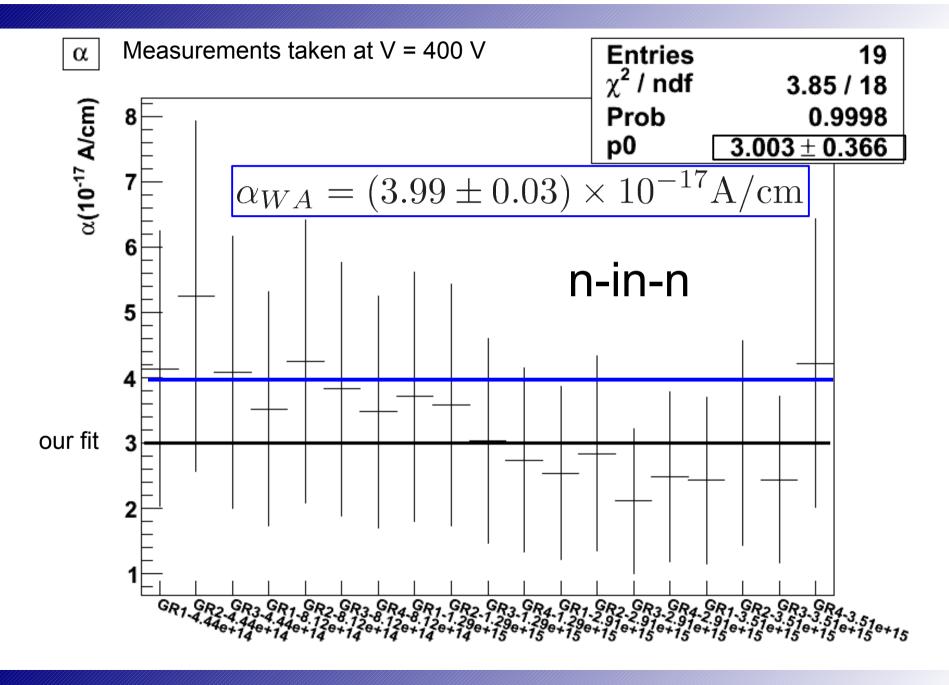
- 24 GeV/c proton at CERN (with step of fluence 2x10¹⁴ to 4x10¹⁵ n_{eq}/cm²)
- MeV neutrons irradiation in Ljubjiana (Up to 1x10¹⁶ n_{eq}/cm²)





Current increase rate

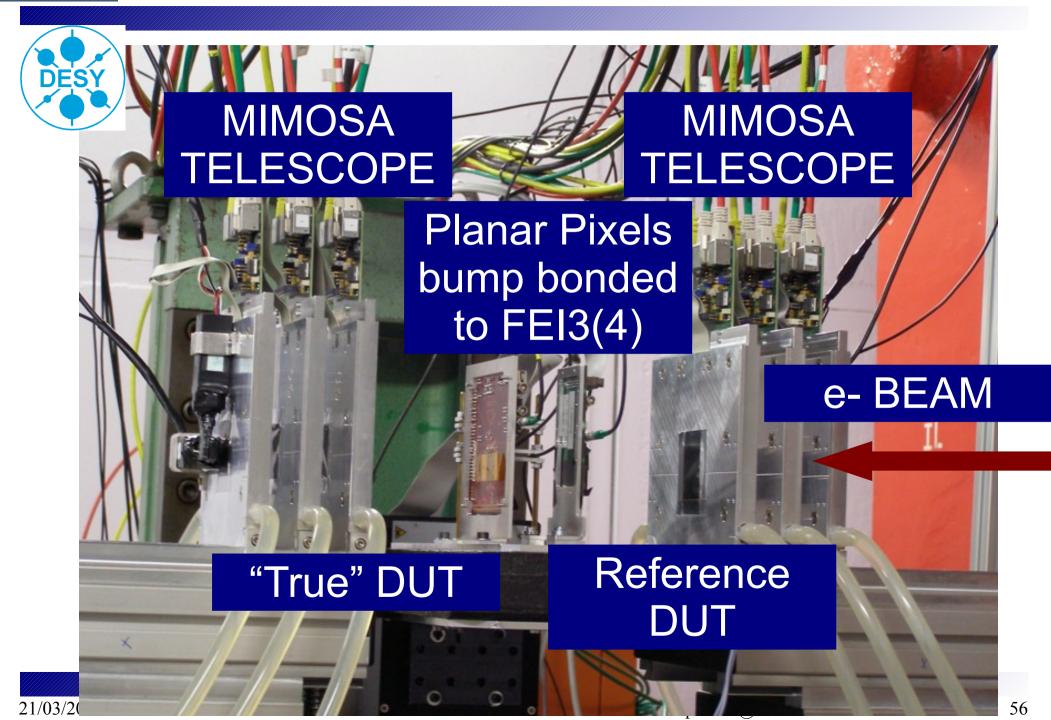






Test beams

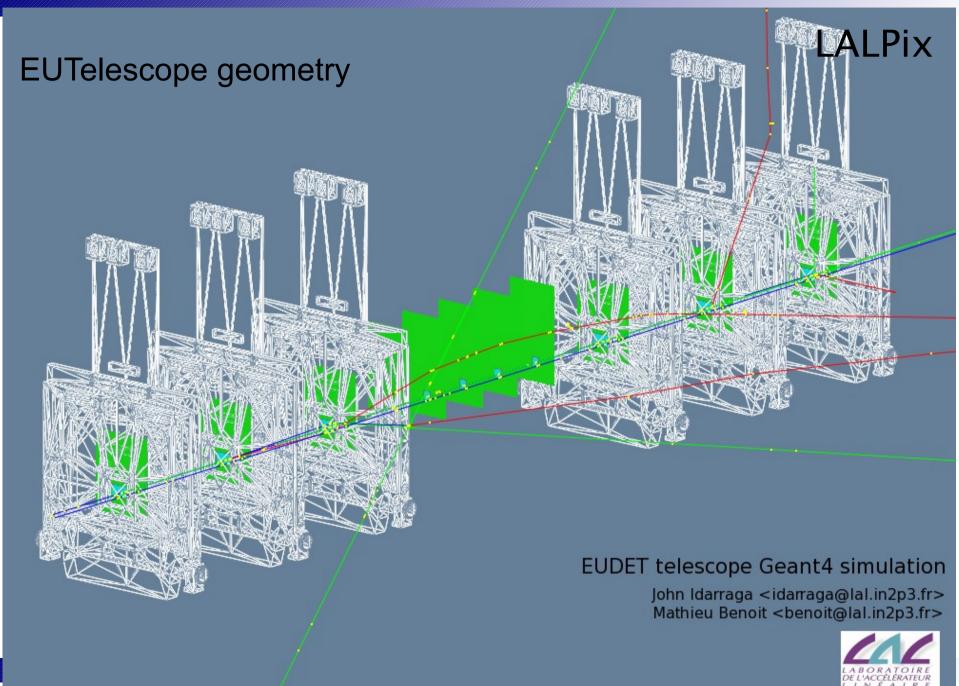






Telescope simulation



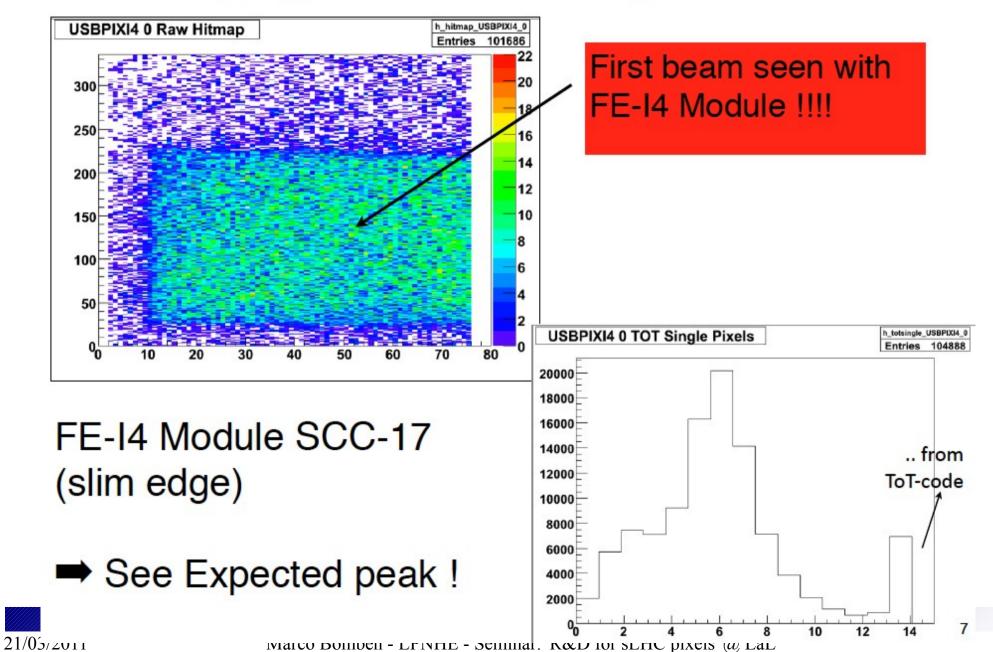




Pictures from a test beam



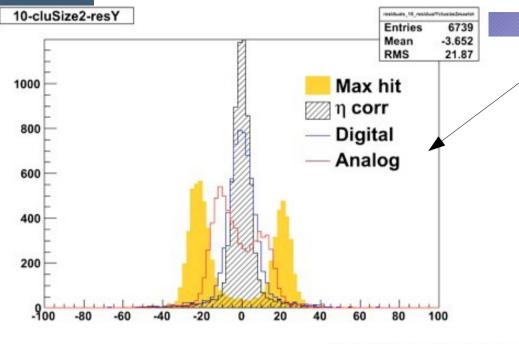
FIRST Highlight from data-taking



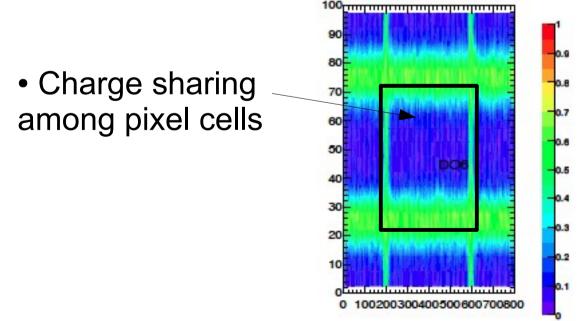


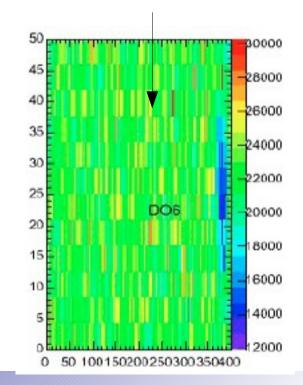
Test beam data analysis





- Space point resolution
 - Different clusteralgorithms are compared
 - Collected charge profile per single cell

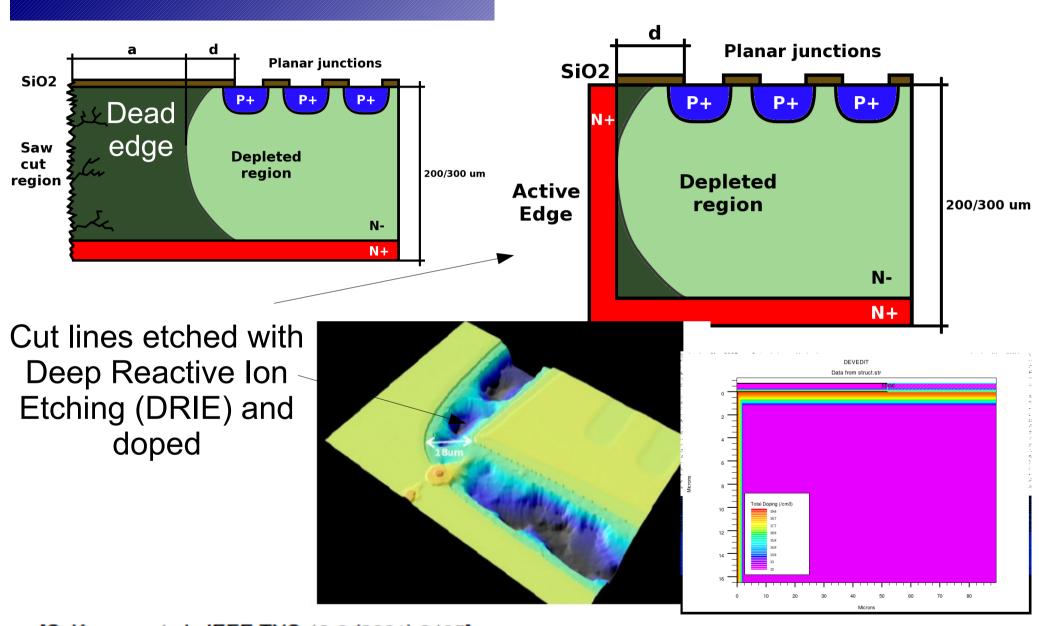






Ideas for new submission





[C. Kenney, et al., IEEE TNS 48-6 (2001) 2405]



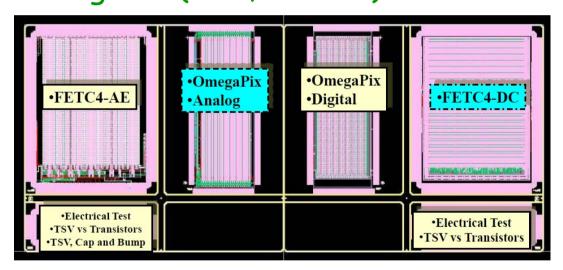
Electronics: collaboration with LaL



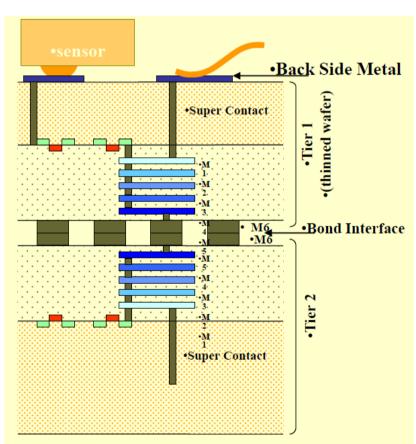
3D/Vertical Integration R&D of the OmegaPix chip

(Chartered Tezzaron)

3D/VI MemDyn circular buffer memory OmegaPix (LAL, LPNHE)



- Exploratory OmegaPix chip (LAL, LPNHE) with small pixel size 50x50 um, matrix of 24 columns x 64 rows
- Goals: low threshold (1000 e), low noise 100 e) low consumption (3 uW/pixel)



Significant support from

IN2P3, ANR, AIDA





CONCLUSIONS



Conclusion & Outlook



- LHC will turn into a High Luminosity machine after 2017
- A completely new detector is needed, coping with higher rates and large radiation fluence
- The PPSU R&D group is working on the new Pixel Tracker for ATLAS
- Key parameters for the new detector are
 - Radiation hardness
 - Low material budget and optimized geometry
 - Charge collection efficiency
- Detailed simulations, and measurements, performed at test beams, after irradiations and on test structures, are driving the new pixel design



That's it!

